

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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BC857AT, BT, CT

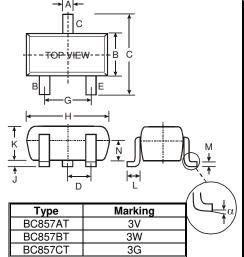
PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Die Construction
- Complementary NPN Types Available (BC847AT,BT,CT)
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 4 and 5)

Mechanical Data

- Case: SOT-523
- Case Material Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Code: See Table Below & Diagram on Page 2
- Ordering & Date Code Information: See Page 2
- Weight: 0.002 grams (approximate)



	SOT-523											
Dim	Min	Max	Тур									
Α	0.15	0.30	0.22									
В	0.75	0.85	0.80									
С	1.45	1.75	1.60									
D			0.50									
G	0.90	1.10	1.00 1.60									
Н	1.50	1.70										
J	0.00	0.10	0.05									
K	0.60	0.80	0.75									
L	0.10	0.30	0.22									
М	0.10	0.20	0.12									
N	0.45	0.65	0.50									
α	0°	8°										
AII D	All Dimensions in mm											

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Collector-Base Voltage		V_{CBO}	-50	V	
Collector-Emitter Voltage		$V_{\sf CEO}$	-45	V	
Emitter-Base Voltage		V_{EBO}	-5.0	V	
Collector Current		Ic	-100	mA	
Power Dissipation	(Note 1)	P_d	150	mW	
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ hetaJA}$	833	°C/W	
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	°C	

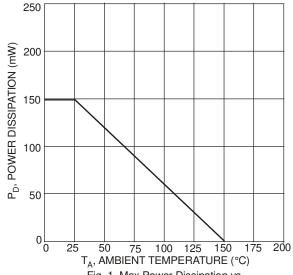
Electrical Characteristics @TA = 25°C unless otherwise specified

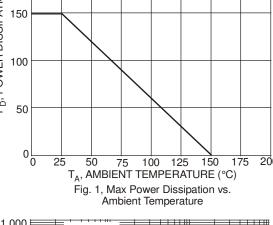
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition			
Collector-Base Breakdown Voltage	(Note 3)	V _{(BR)CBO}	-50	_	_	V	$I_C = 10\mu A, I_B = 0$			
Collector-Emitter Breakdown Voltage	(Note 3)	V _{(BR)CEO}	-45	_	_	V	$I_C = 10 \text{mA}, I_B = 0$			
Emitter-Base Breakdown Voltage	(Note 3)	$V_{(BR)EBO}$	-5	_	_	V	$I_E = 1 \mu A, I_C = 0$			
DC Current Gain (Note 3)	Current Gain A		125	_	250					
	В	h _{FE}	220	290	475	_	$V_{CE} = -5.0V, I_{C} = -2.0mA$			
	C		420	520	800					
Collector-Emitter Saturation Voltage	(Note 3)	V-=	_	_	-300 -650	mV	$I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$			
Collector-Emitter Saturation Voltage	(Note 3)	$V_{CE(SAT)}$				IIIV	$I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$			
Base-Emitter Saturation Voltage	(Note 3)	V _{BE(SAT)}	_	-700 -900	_	mV	$I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$			
Dase-Emilier Saluration voltage	(Note 3)				_	111 V	$I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$			
Paga Emittar Valtaga	(Note 3)	V _{BE(ON)}	-600	_	-750 -820	mV	$V_{CE} = -5.0V, I_{C} = -2.0mA$			
Base-Emitter Voltage	(Note 3)		_				$V_{CE} = -5.0V, I_{C} = -10mA$			
Collector-Cutoff Current	(Note 2)		_	_	-15	NA	$V_{CB} = -30V$			
Collector-Cutoff Current	(Note 3)	I _{CBO}	_		-4.0	μΑ	V _{CB} = -30V, T _A = 150°C			
Gain Bandwidth Product		f _T	100	_	_	MHz	V _{CE} = -5.0V, I _C = -10mA, f = 100MHz			
Output Capacitance		C _{OB}	_	_	4.5	pF	V _{CB} = -10V, f = 1.0MHz			
							$I_C = -0.2 \text{mA}, V_{CE} = -5.0 \text{Vdc},$			
Noise Figure	NF	_	_	10	dB	$R_S = 2.0K\Omega$, $f = 1.0KHz$,				
							BW = 200Hz			

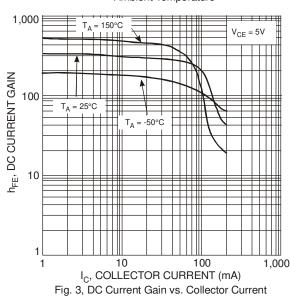
Notes:

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead
- 3. Short duration pulse test used to minimize self-heating effect.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.









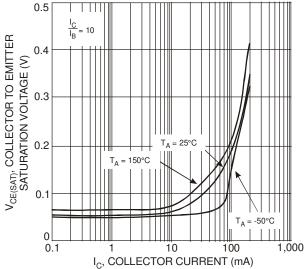


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

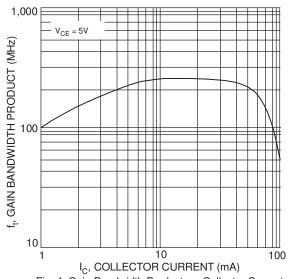


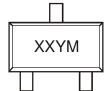
Fig. 4, Gain Bandwidth Product vs. Collector Current

Ordering Information (Note 6)

Device	Packaging	Shipping				
BC857AT-7-F	SOT-523	3000/Tape & Reel				
BC857BT-7-F	SOT-523	3000/Tape & Reel				
BC857CT-7-F	SOT-523	3000/Tape & Reel				

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XX = Product Type Marking Code (See Page 1), e.g. 3V = BC857AT

YM = Date Code Marking

Y = Year (ex: N = 2002)

M = Month (ex: 9 = September)

Date Code Key

Code	Jan	10		2	/	May	00		7	o	ОСР	001	, ,	N	D00
Month	Jan	Fe	h	Mar	Apr	Mav	Ju	n	Jul	Aug	Sep	Oct	· N	lov	Dec
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Χ	Υ	Z
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Date Code Rey															



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